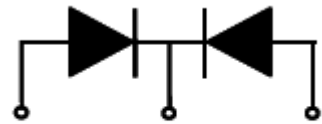


Product Specification

GOODARK Type
MBR20150CT

Construction : Schottky Barrier Rectifier
Application : For General Purpose
(Manufacturer) :
Suzhou Goodark Electronics Co.,Ltd
Prepared on Sep. 17th, 2008
Prepared: R & D Department
Approval: QRA Department



1. Anode 2. Cathode 3. Anode

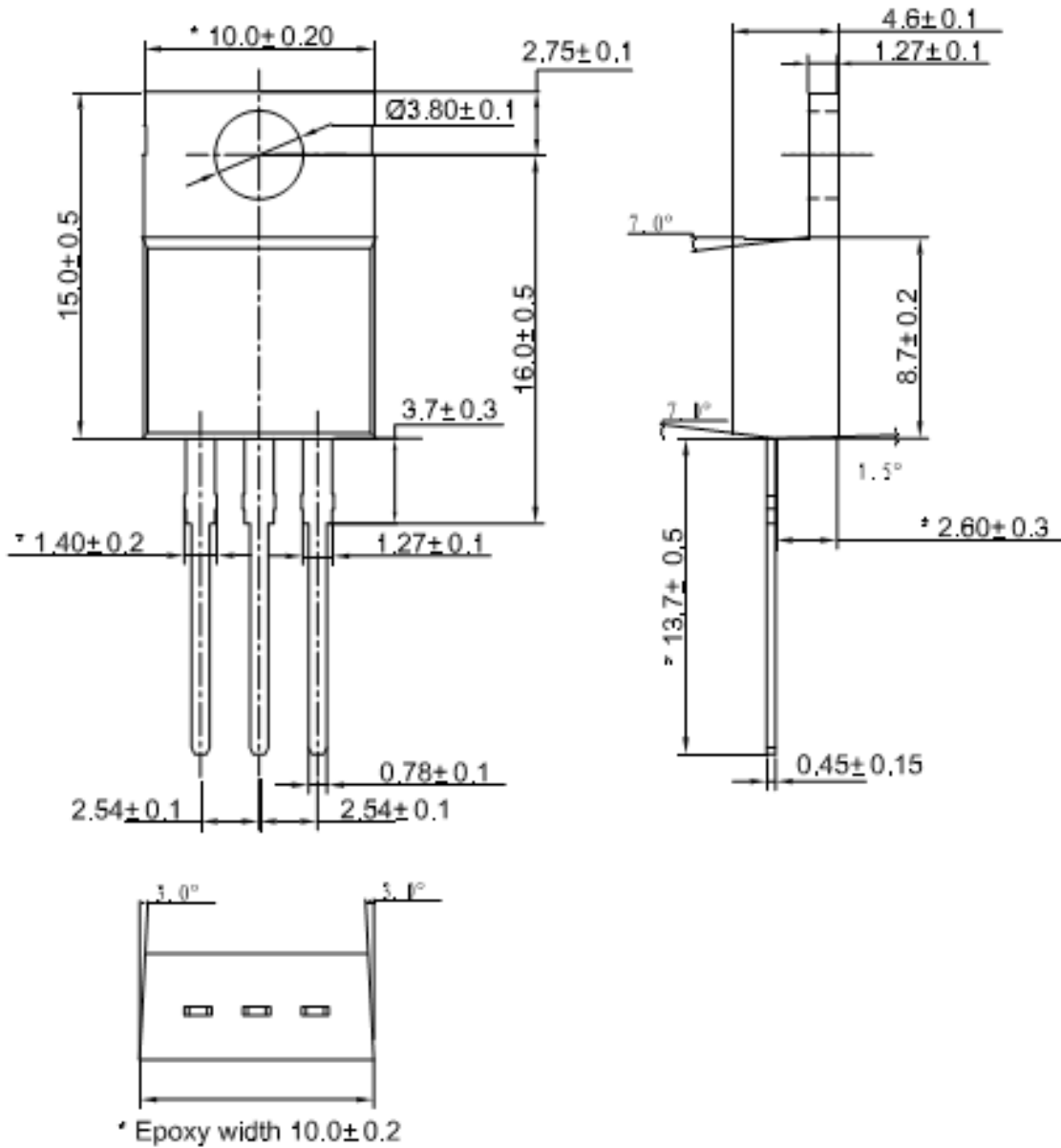
SCHOTTKY BARRIER RECTIFIER
20 AMPERES
150 VOLTS

CONTENTS

1. Package Outline
2. Marking
3. Features& Mechanical Characteristics
4. Maximum Ratings and Electrical Characteristics
5. Rating and characteristic Curves
6. Packing Specification PACKAGING SPECIFICATION
7. Description of Box Label

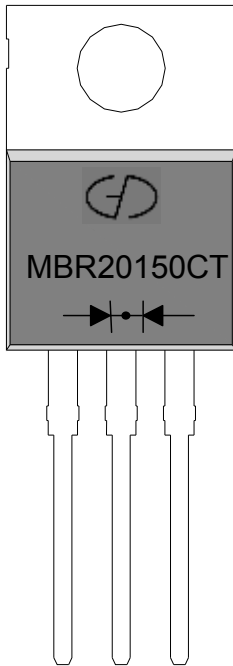
1. Package Outline (TO220-3L)

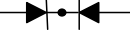
UNIT:mm



Lead Frame Material : Copper Plating: Pure Tin Plating

2.MARKING



1. Part Name : MBR20150CT
2. Logo Mark: 
3. Polarity: 

3.Features& Mechanical Characteristics

Features

- Plastic package has underwriters Laboratory Flammability Classification 94V-0
- Dual rectifier construction, positive center tap
- Metal of silicon rectifier, majority carrier conduction
- Low forward voltage, high efficiency
- Guarding for over voltage protection
- For use in low voltage, high frequency inverters,
- Free wheeling, and polarity protection applications

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max.for10 sec
- Shipped 50 units per plastic tube

4.Maximum Ratings and Electrical Characteristics

MAXIMUM RATINGS and ELECTRICAL CHARACTERISTICS(TC=25°C unless otherwise moted)					
PARAMETER	TEST CONDITIONS		SYMBOL	MBR20150CT	UNIT
Maximum repetitive peak reverse voltage			VRRM	150	V
Working peak reverse voltage			VRWM	150	V
Maximum DC blocking voltage			VDC	150	V
Maximum average forward rectified current at Tc=105°C total device per diode			IF(AV)	20 10	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode			IFSM	150	A
Peak repetitive reverse current per leg at tp=2.0us , 1KHz			IRRM	1.0	A
Voltage rate of change (rated VR)			DV/dt	10000	V/us
Operating junction temperature range			TJ	—55 to+150	°C
Storage temperature range			TSTG	—55 to+150	°C
Isolation voltage (TO220F-AB only) from terminal to heatsink t = 1 sec			VAC	1500	V
Maximum instantaneous forward voltage per leg	IF=10A IF=10A	TC=25°C TC=125°C	VF	0.92 0.82	V
Maximum reverse current per leg at working peak Reverse voltage		TJ=25°C TJ=100°C	IR	200 15	uA mA

Thermal Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Max	Unit
RθJC	Thermal Resistance, Junction to Case per Leg	2.0	°C /W
RθJA	Thermal Resistance, Junction to Ambient per Leg	62.5	°C /W

Note:

1. Screw mounting with 4-40 screw, where washer diameteris≤4.9mm(0.19 ")
2. Pulse test:300us pulse width,1% duty cycle

5. Rating and Characteristic Curves

($T_c=25^\circ\text{C}$ Unless otherwise noted)

Fig. 1: Average forward power dissipation versus average forward current (per diode).

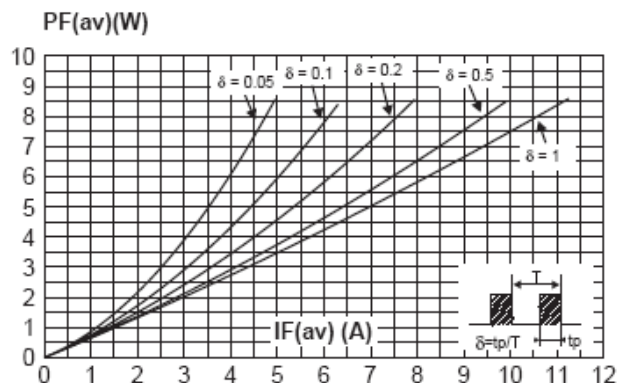


Fig. 2: Average forward c temperature ($\delta = 0.5$, per diode).

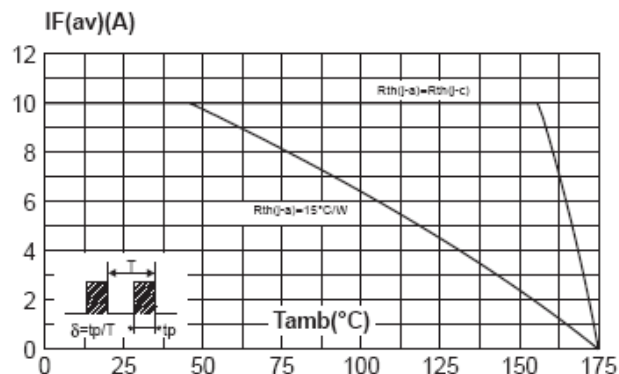


Fig. 3: Non repetitive surge peak forward current versus overload duration (maximum values, per diode).

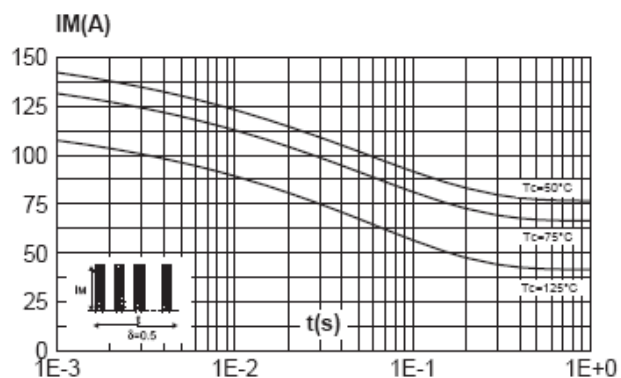


Fig. 4: Relative variation of thermal impedance junction to case versus pulse duration (per diode).

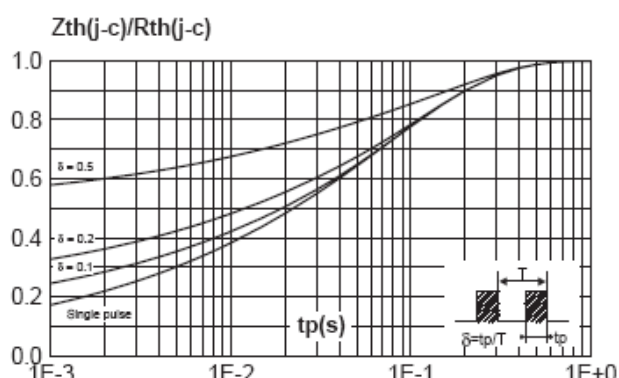


Fig. 5: Reverse leakage current versus reverse voltage applied (typical values, per diode).

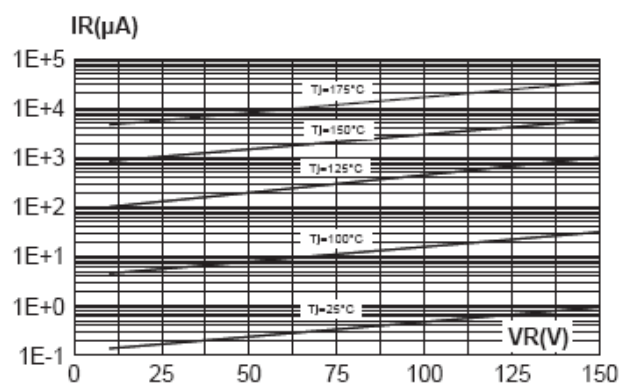
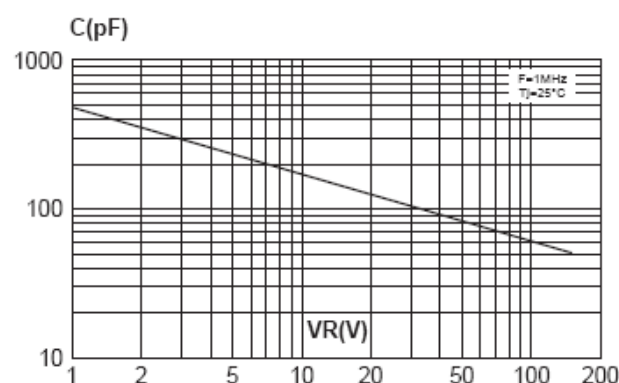
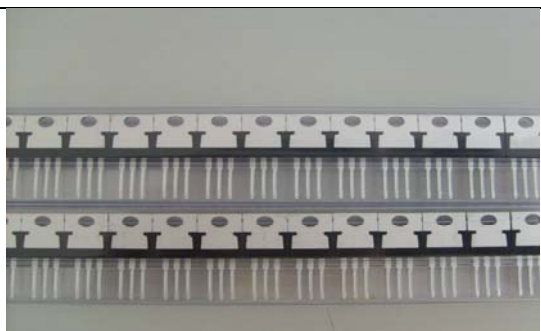


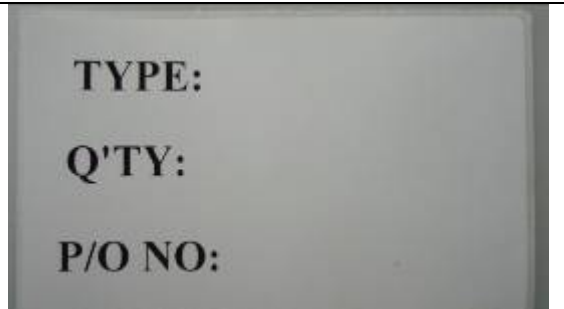
Fig. 6: Junction capacitance versus reverse voltage applied (typical values, per diode).



6. Packing Specification

	
1) Tube : 50units	2) Inner Box: 20 tube(1000units)
	
3) Outer Box: 10 inner box (10,000units)	

7. DESCRIPTION of BOX LABEL

	
1) Inner Box Label	2) Inner Box Label
	
3) Outer Box Label	4) Outer Box Label